

PC815 Series

- ✱ Lead forming type (I type) and taping reel type (P type) are also available. (PC815I/PC815P)
- ✱ TÜV (VDE0884) approved type is also available as an option.

■ Features

1. High current transfer ratio
(CTR: MIN. 600% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
2. High isolation voltage between input and output
($V_{iso} : 5000V_{rms}$)
3. Compact dual-in-line package

PC815 : 1-channel type

PC825 : 2-channel type

PC835 : 3-channel type

PC845 : 4-channel type

High Sensitivity, High Density Mounting Type Photocoupler

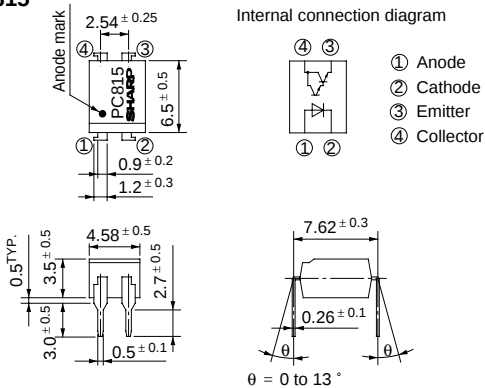
■ Applications

1. System appliances, measuring instruments
2. Industrial robots
3. Copiers, automatic vending machines
4. Signal transmission between circuits of different potentials and impedances

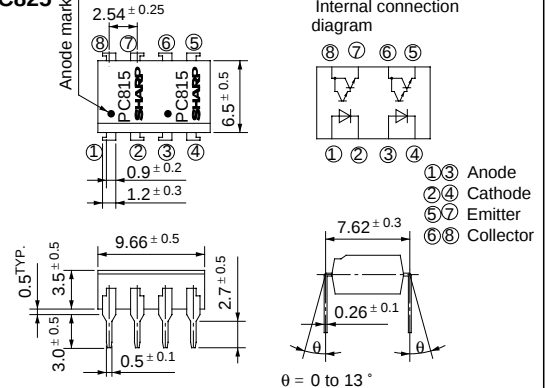
■ Outline Dimensions

(Unit : mm)

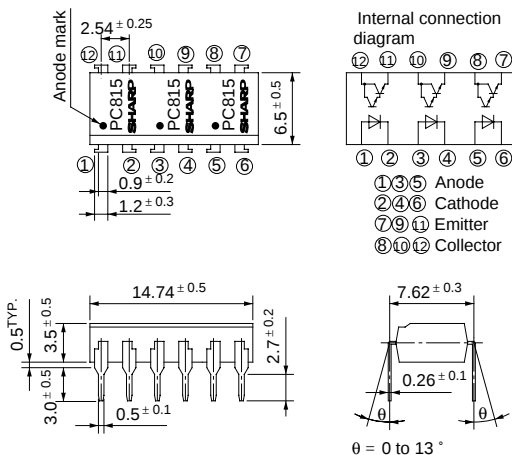
PC815



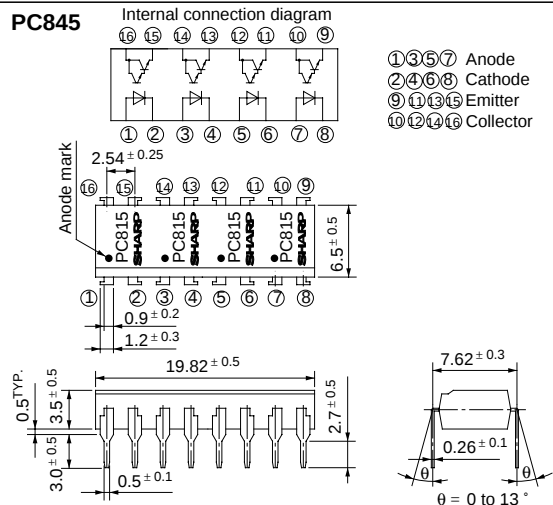
PC825



PC835



PC845



■ Absolute Maximum Ratings (Ta= 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	*1 Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _C	80	mA
	Collector power dissipation	P _C	150	mW
Total power dissipation		P _{tot}	200	mW
*2 Isolation voltage		V _{iso}	5 000	V _{rms}
Operating temperature		T _{opr}	- 30 to + 100	°C
Storage temperature		T _{stg}	- 55 to + 125	°C
*3 Soldering temperature		T _{sol}	260	°C

*1 Pulse width<=100 μs, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics (Ta= 25°C)

Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage		V _F	I _F = 20mA	-	1.2	1.4	V
	Peak forward voltage		V _{FM}	I _{FM} = 0.5A	-	-	3.0	V
	Reverse current		I _R	V _R = 4V	-	-	10	μ A
	Terminal capacitance		C _t	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark current		I _{CEO}	V _{CE} = 10V, I _F = 0	-	-	10 ⁻⁶	A
Transfer charac- teristics	Current transfer ratio		CTR	I _F = 1mA, V _{CE} = 2V	600	-	7 500	%
	Collector-emitter saturation voltage		V _{CE(sat)}	I _F = 20mA, I _C = 5mA	-	0.8	1.0	V
	Isolation resistance		R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω
	Floating capacitance		C _f	V = 0, f = 1MHz	-	0.6	1.0	pF
	Cut-off frequency		f _c	V _{CE} = 2V, I _C = 2mA, R _L = 100 Ω	1	6	-	kHz
	Response time	Rise time	t _r	V _{CE} = 2V, I _C = 10mA, R _L = 100Ω	-	60	300	μ s
		Fall time	t _f		-	53	250	μ s

Fig. 1 Forward Current vs. Ambient Temperature

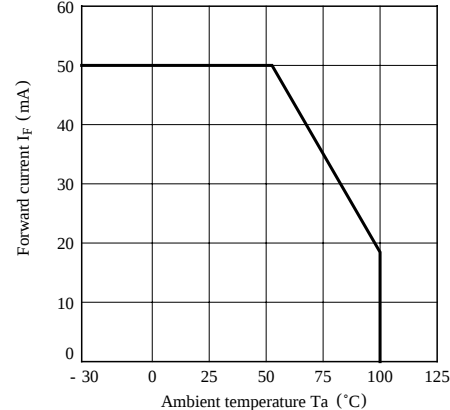


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

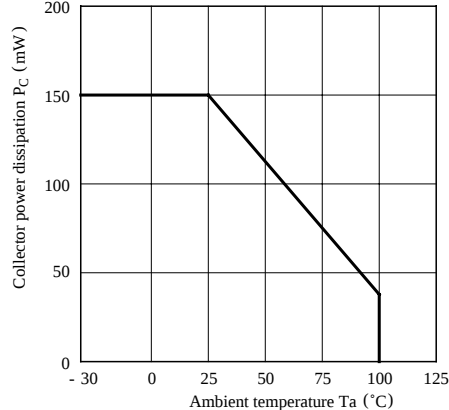


Fig. 3 Peak Forward Current vs. Duty Ratio

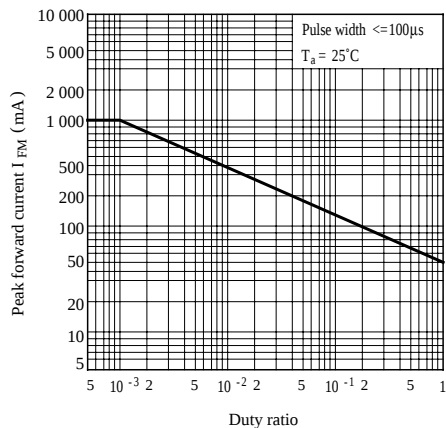


Fig. 4 Forward Current vs. Forward Voltage

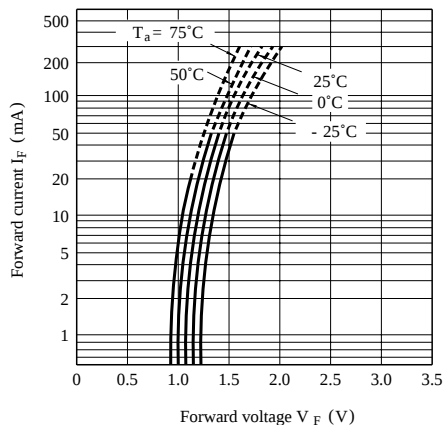


Fig. 5 Current Transfer Ratio vs. Forward Current

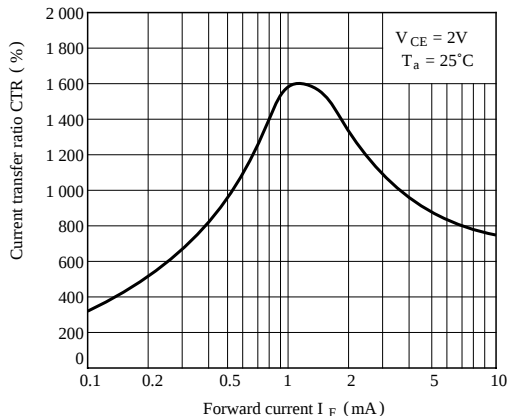


Fig. 6 Collector Current vs. Collector-emitter Voltage

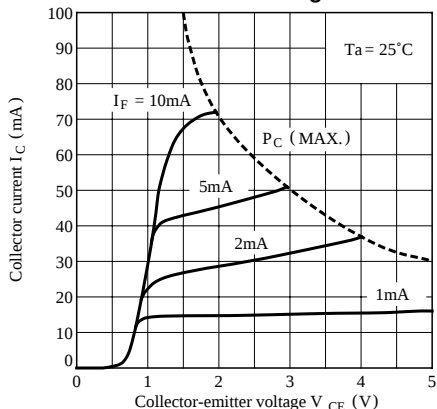


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

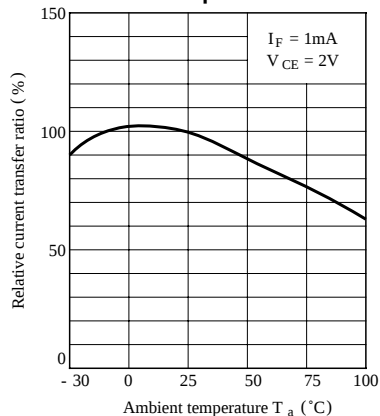


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

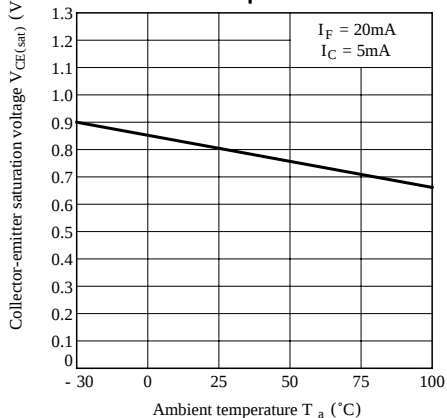


Fig. 9 Collector Dark Current vs. Ambient Temperature

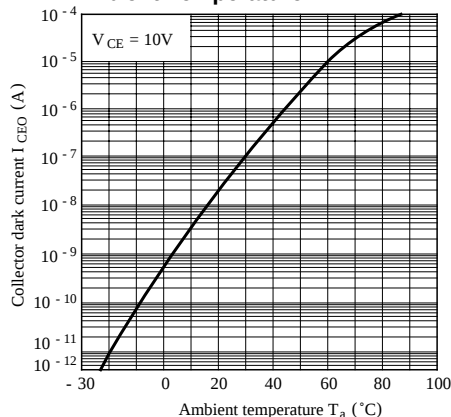


Fig.10 Response Time vs. Load Resistance

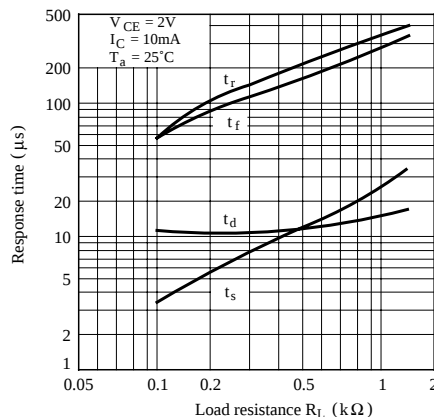
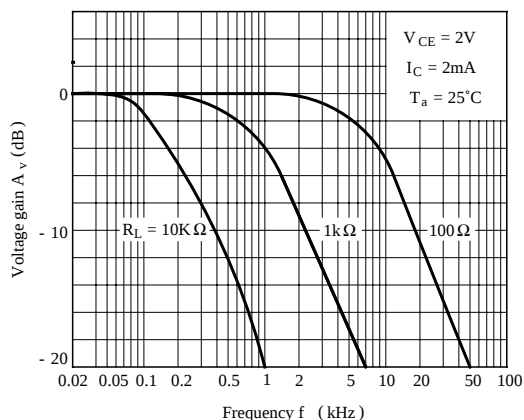


Fig.11 Frequency Response



Test Circuit for Response Time

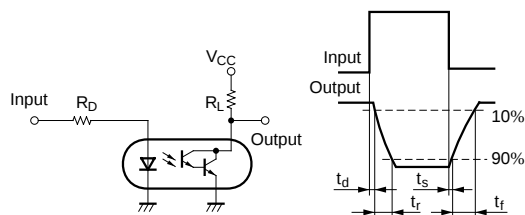
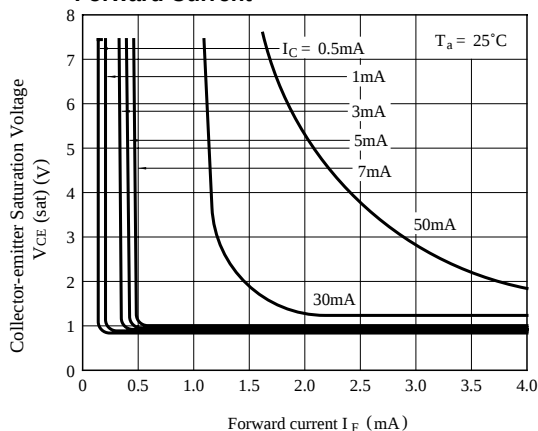


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Test Circuit for Frequency Response

